May 2010



KSC5305D NPN Silicon Transistor

Features

- High Voltage High Speed Power Switch Application
- · Built-in Free-wheeling Diode makes efficient anti saturation operation
- Suitable for half bridge light ballast Applications
- No need to interest an h_{FE} value because of low variable storage-time spread even though corner spirit product
- · Low base drive requirement



Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector Base Voltage	800	V
V _{CEO}	Collector Emitter Voltage	400	V
V _{EBO}	Emitter Base Voltage	12	V
۱ _C	Collector Current (DC)	5	Α
I _{CP}	*Collector Current (Pulse)	10	Α
Ι _Β	Base Current (DC)	2	А
I _{BP}	*Base Current (Pulse)	4	Α
P _C	Power Dissipation (T _C =25°C)	75	W
Τ _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 to 150	°C

* Pulse Test : Pulse Width = 5mS, Duty cycles \leq 10%

Thermal Characteristics

Symbol	Parameter		Rating	Units	
R _{θjc}	Thermal Resistance	Junction to Case	1.65	°C/W	
$R_{ heta ja}$		Junction to Ambient	62.5	°C/W	

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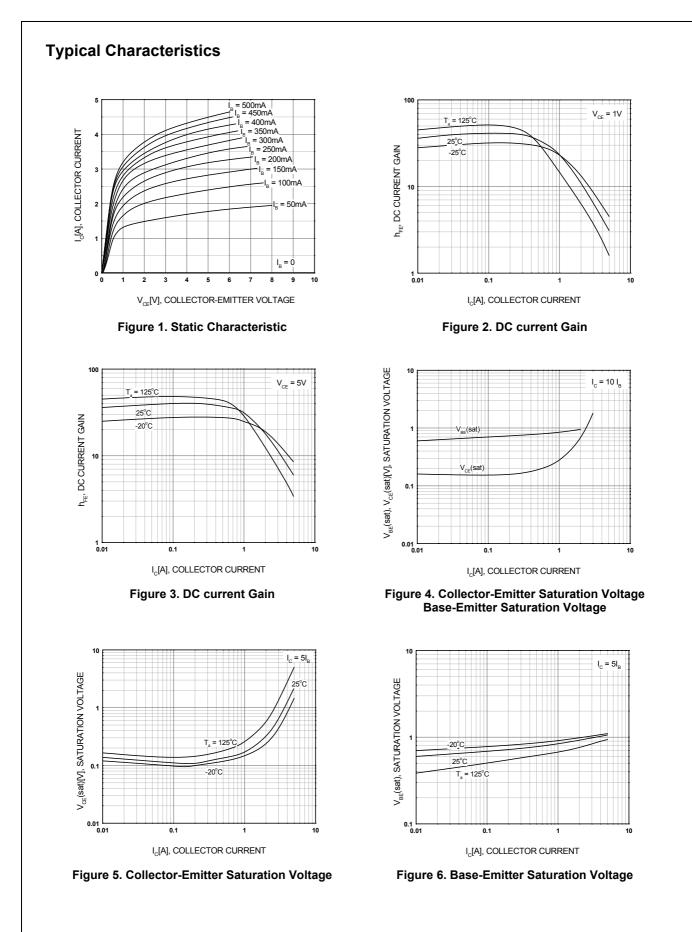
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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =1mA, I _E =0	800	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	400	-	-	V
BV_{EBO}	Emitter-Base Breakdown Voltage	I _E =1mA, I _C =0	12	-	-	V
I _{CBO}	Collector Cut-off Current	V _{CB} =500V, I _E =0	-	-	10	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 9V, I _C = 0	-	-	10	μA
h _{FE1} h _{FE2}	DC Current Gain	V _{CE} =1V, I _C =0.8A V _{CE} =1V, I _C =2A	22 8	-	-	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =0.8A, I _B =0.08A I _C =2A, I _B =0.4A	-	-	0.4 0.5	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =0.8A, I _B =0.08A I _C =2A, I _B =0.4A	-	-	1.0 1.0	V V
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz	-	-	75	pF
t _{ON}	Turn On Time	V _{CC} =300V, I _C =2A,	-	-	150	ns
t _{STG}	Storage Time	I _{B1} =0.4A, I _{B2} =-1A,	-	-	2	μS
t _F	Fall Time	R_L =150 Ω	-	-	0.2	μS
t _{STG}	Storage Time	V _{CC} =15V, V _Z =300V,	-	-	2.25	μS
t _F	Fall Time	I _C =2A, I _{B1} =0.4A, I _{B2} =-0.4A, L _C =200μH	-	-	150	ns
V _F	Diode Forward Voltage	I _F =1A	-	-	1.5	V
		I _F =2A	-	-	1.6	V
t _{rr}	* Reverse recovery time	I _F =0.4A	-	800	-	ns
	(di/dt = 10A/µs)	I _F =1A I _F =2A	-	1.4 1.9	-	μS μS

Electrical Characteristics T_a=25°C unless otherwise noted

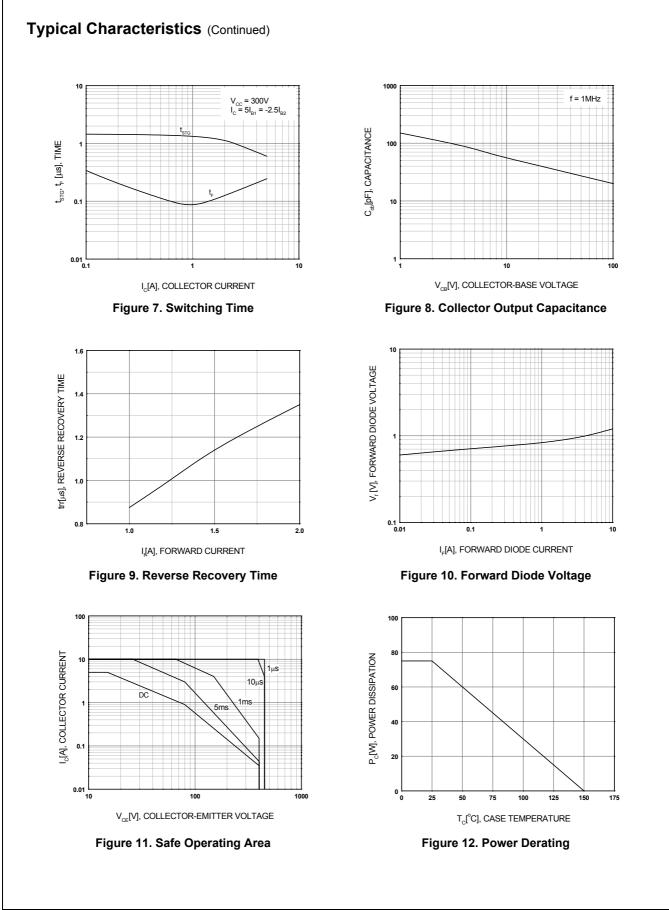
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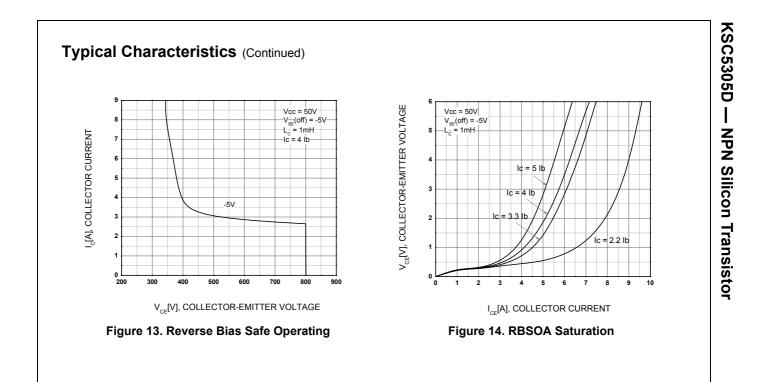


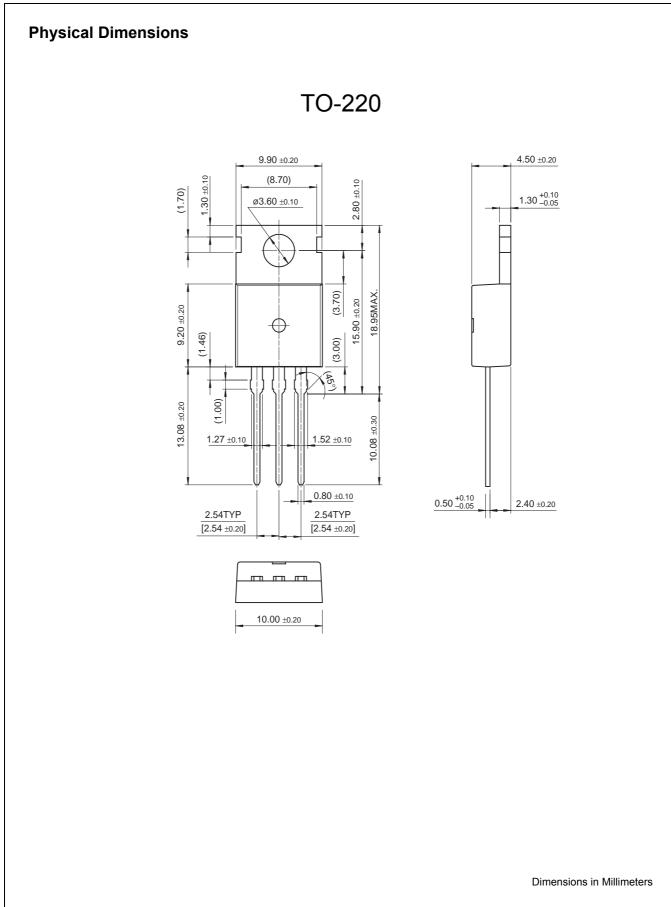
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